NSN 5961-01-433-2383

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-433-2383 **Inclosure Material:** Glass **Overall Length:** 2.660 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.060 inches and 0.090 inches **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 39.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 8.30 milliamperes repetitive peak forward current **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/533 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0